# V6K100DU

Vishay General Semiconductor

## High Current Density Surface-Mount Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.44$  V at  $I_F = 1.5$  A



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3 and / or 4 o 5, 6

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## **DESIGN SUPPORT TOOLS**



| PRIMARY CHARACTERISTICS  |                   |  |  |  |  |
|--|-------------------|--|--|--|--|
| I <sub>F(AV)</sub>   | 2 x 3 A           |  |  |  |  |
| V <sub>RRM</sub>   | 100 V             |  |  |  |  |
| I <sub>FSM</sub>   | 80 A              |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> = 3 A (T <sub>A</sub> = 125 °C) | 0.55 V            |  |  |  |  |
| T <sub>J</sub> max.  | 150 °C            |  |  |  |  |
| Package  | FlatPAK 5 x 6     |  |  |  |  |
| Circuit configuration  | Separated cathode |  |  |  |  |

## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C



AUTOMOTIVE GRADE

Available

- AEC-Q101 qualified available
  Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **TYPICAL APPLICATIONS**

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

### **MECHANICAL DATA**

Case: FlatPAK 5 x 6

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)                       |                                   |             |      |  |  |
|--|-----------------------------------|-------------|------|--|--|
| PARAMETER  | SYMBOL                            | V6K100DU    | UNIT |  |  |
| Device marking code  |                                   | V610D       |      |  |  |
| Maximum repetitive peak reverse voltage  | V <sub>RRM</sub>                  | 100         | V    |  |  |
| Maximum DC forward oursant par diada   | I <sub>F(AV)</sub> <sup>(1)</sup> | 3           | А    |  |  |
| Maximum DC forward current per diode   | I <sub>F(AV)</sub> <sup>(2)</sup> | 2.2         | А    |  |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I <sub>FSM</sub>                  | 80          | A    |  |  |
| Operating junction temperature range   | T <sub>J</sub> <sup>(3)</sup>     | -40 to +150 | °C   |  |  |
| Storage temperature range  | T <sub>STG</sub>                  | -55 to +150 | °C   |  |  |

#### Notes

(1) With infinite heatsink

<sup>(2)</sup> Free air, mounted on recommended pad area

 $^{(3)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{0JA}$ 

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| ELECTRICAL CHARACTERIS                  | <b>FICS</b> (T <sub>A</sub> = 25  | 5 °C unless of            | therwise note      | d)   |      |      |
|---|---|---------------------------|--------------------|------|------|------|
| PARAMETER                               | TEST CONDITIONS   |                           | SYMBOL             | TYP. | MAX. | UNIT |
|   | I <sub>F</sub> = 1.5 A  | T <sub>A</sub> = 25 °C    | V <sub>F</sub> (1) | 0.50 | -    | V    |
| Instantaneous forward voltage per diode | I <sub>F</sub> = 3 A  |                           |                    | 0.61 | 0.69 |      |
| instantaneous loiward voltage per diode | I <sub>F</sub> = 1.5 A  | - T <sub>A</sub> = 125 °C |                    | 0.44 | -    |      |
|   | I <sub>F</sub> = 3 A  |                           |                    | 0.55 | 0.63 |      |
|   | V <sub>B</sub> = 70 V   | T <sub>A</sub> = 25 °C    | <sub>R</sub> (2)   | 0.01 | -    | mA   |
| Reverse current per diode               | v <sub>R</sub> = 70 v   | T <sub>A</sub> = 125 °C   |                    | 2    | -    |      |
| neverse current per diode               | $V_{R} = 100 V \qquad \frac{T_{A} = 25 \text{ °C}}{T_{A} = 125 \text{ °C}}$ | T <sub>A</sub> = 25 °C    |                    | -    | 0.35 |      |
|   |   | T <sub>A</sub> = 125 °C   |                    | 4    | 12   |      |
| Typical junction capacitance per diode  | 4.0 V, 1 MHz  |                           | CJ                 | 360  | -    | pF   |

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}\,$  Pulse test: pulse width  $\leq 5\mbox{ ms}$ 

| <b>THERMAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                                 |      |      |      |
|--|---------------------------------|------|------|------|
| PARAMETER  | SYMBOL                          | TYP. | MAX. | UNIT |
| Thermal registeres per diade   | R <sub>0JA</sub> (1)(2)         | 100  | -    | °C/W |
| Thermal resistance per diode   | R <sub>0JM</sub> <sup>(3)</sup> | 3.5  | 4.5  | 0/11 |

#### Notes

 $^{(1)}$  The heat generated must be less than thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

 $^{(2)}$  Free air, mounted on recommended copper pad area; thermal resistance R<sub> $ext{BJA}$ </sub> - junction-to-ambient

 $^{(3)}$  Mounted on infinite heat sink; thermal resistance  $R_{\theta JM}$  - junction-to-mount

| ORDERING INFORMATION (Example) |                 |                        |               |                                    |  |
|--------------------------------|-----------------|------------------------|---------------|------------------------------------|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |  |
| V6K100DU-M3/H                  | 0.10            | Н                      | 1500          | 7" diameter plastic tape and reel  |  |
| V6K100DU-M3/I                  | 0.10            | I                      | 6000          | 13" diameter plastic tape and reel |  |
| V6K100DUHM3/H (1)              | 0.10            | Н                      | 1500          | 7" diameter plastic tape and reel  |  |
| V6K100DUHM3/I <sup>(1)</sup>   | 0.10            | l                      | 6000          | 13" diameter plastic tape and reel |  |

Note

(1) AEC-Q101 qualified



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## **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

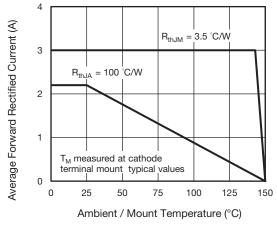


Fig. 1 - Maximum Forward Current Derating Curve

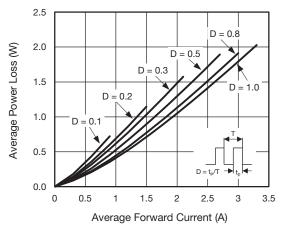


Fig. 2 - Forward Power Loss Characteristics

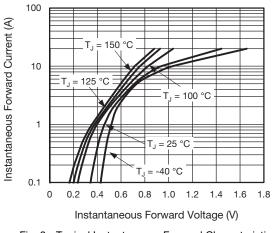
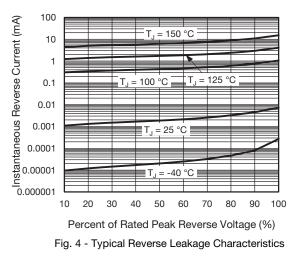


Fig. 3 - Typical Instantaneous Forward Characteristics





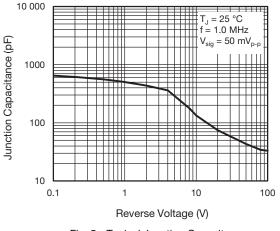


Fig. 5 - Typical Junction Capacitance

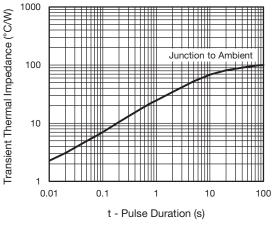


Fig. 6 - Typical Transient Thermal Impedance

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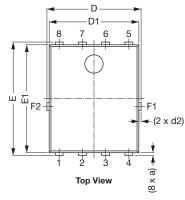
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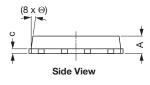
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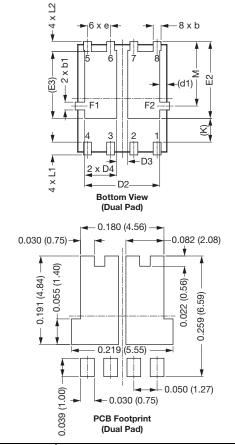


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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)







| DIM. MIN. |       | INCHES    |       |      | MILLIMETERS |      |  |
|-----------|-------|-----------|-------|------|-------------|------|--|
|           | NOM.  | MAX.      | MIN.  | NOM. | MAX.        |      |  |
| А         | 0.035 | 0.039     | 0.043 | 0.89 | 0.99        | 1.09 |  |
| (a)       | -     | 0.006     | -     | -    | 0.15        | -    |  |
| b         | 0.013 | 0.017     | 0.020 | 0.32 | 0.43        | 0.52 |  |
| b1        | 0.013 | 0.017     | 0.020 | 0.32 | 0.43        | 0.52 |  |
| С         | 0.008 | -         | 0.014 | 0.20 | -           | 0.35 |  |
| D         | 0.197 | 0.203     | 0.209 | 5.00 | 5.15        | 5.30 |  |
| D1        | 0.189 | 0.193     | 0.197 | 4.80 | 4.90        | 5.00 |  |
| D2        | 0.154 | 0.161     | 0.169 | 3.90 | 4.10        | 4.30 |  |
| D3        | 0.020 | 0.024     | 0.031 | 0.50 | 0.60        | 0.80 |  |
| D4        | 0.063 | 0.069     | 0.075 | 1.60 | 1.75        | 1.90 |  |
| (d1)      | -     | 0.016     | -     | -    | 0.40        | -    |  |
| (d2)      | -     | 0.005     | -     | -    | 0.125       | -    |  |
| E         | 0.238 | 0.244     | 0.250 | 6.05 | 6.20        | 6.35 |  |
| E1        | 0.228 | 0.232     | 0.236 | 5.80 | 5.90        | 6.00 |  |
| E2        | 0.157 | 0.165     | 0.173 | 4.00 | 4.20        | 4.40 |  |
| (E3)      | -     | 0.144     | -     | -    | 3.65        | -    |  |
| е         |       | 0.050 BSC |       |      | 1.27 BSC    |      |  |
| (K)       | 0.039 | -         | -     | 1.00 | -           | -    |  |
| L1        | 0.019 | -         | 0.043 | 0.48 | -           | 1.10 |  |
| L2        | 0.012 | -         | 0.031 | 0.30 | -           | 0.80 |  |
| М         | 0.128 | 0.138     | 0.148 | 3.25 | 3.50        | 3.75 |  |
| Θ         | 0°    | -         | 10°   | 0°   | -           | 10°  |  |

#### Notes

• Dimensioning and tolerancing per ASME Y14.5-2009

Dimensions D1 and E1 do not include mold flash or gate burrs

• Dimension (XX) means reference only

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